Statistics of current uctuations at non-zero frequencies

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We formulate a general approach which describes statistics of current uctuations in mesoscopic coherent conductors at arbitrary frequencies and in the presence of interactions. Applying this approach to the non-interacting case, we analyze frequency dispersion of the third cumulant of the current operator S_3 at frequencies wellbelow both the inverse charge relaxation time and the inverse electron dwell time. This dispersion turns out to be important in the frequency range comparable to applied voltages. For comparatively transparent conductors it may lead to the sign change of S_3 .

Investigations of current uctuations in mesoscopic conductors can provide a great deal of inform ation about properties of such systems. During last years much attention has been devoted to shot noise. Experimental and theoretical studies of the second moment of the current operator describing shot noise revealed a rich variety of properties caused by an interplay between scattering, quantum coherence and charge discreteness. Furthermore, such studies can substantially deepen our understanding of the role of electron-electron interactions in mesoscopic transport because shot noise and interaction e ects are known to be closely related.

O ne can also go beyond the second m om ent and study higher order correlators of the current operator thereby extending the amount of information already obtained from investigations of electron transport and shot noise. Recently the rst experimental study of the third current cumulant in mesoscopic tunnel junctions was reported 4 .

A theoretical fram ework which enables one to analyze statistics of charge transfer in m esoscopic conductors was developed in Ref. 5. This theory of full counting statistics (FCS) allows to evaluate any cumulant of the current operator in the absence of interactions and in the zero frequency limit. Under these conditions higher order current cumulants were investigated by a number of authors 6,7,8,9 . In order to include interactions and to analyze frequency dispersion of current uctuations it is necessary to go beyond the FCS theory and to develop a more general real time path integral technique 2,10 .

The goal of the present paper is to address statistics of current uctuations at non-zero frequencies. We rst present a general and form ally exact expression for the real time e ective action of a coherent conductor described by an arbitrary energy independent scattering matrix. This expression enables one to fully describe interaction e ects in such type of conductors. We will then demonstrate that in a non-interacting case this e ective action provides a direct generalization of the FCS generating function to non-zero frequencies. With the aid of our technique we will analyze the frequency dispersion of the third cumulant of the current operator in mesoscopic coherent conductors.

It is worthwhile to point out that the frequency dependence of current correlators can be caused by various reasons. One of them is the e ect of an external electrom agnetic environment which is important for quantitative interpretation of the experimentally detected behavior of higher cum ulants 11 . A nother source of the frequency dispersion is the internal dynamics of a quantum scatterer. Here the important time scales are the corresponding RC-time $_{\rm RC}$ and the electron dwell time $_{\rm D}$ inside the conductor. The latter scale was recently taken into consideration in the analysis of the second 12 and the third 13 current cumulants for chaotic quantum dots.

In this paper we will address current uctuations at frequencies not directly related to any of such scales. We will demonstrate that apart from the above mechanisms there exists an additional { intrinsic { frequency dispersion of the current correlators at the scale set by the voltage drop V across the conductor. Since V can vary in a wide range, this dependence is in general important and should be taken into account while interpreting the experimental results. In particular, in the absence of interactions the third cumulant of the current operator S_3 is fully determined by the two parameters:

$$= \frac{P}{\frac{1}{P}} \frac{T_n (1 - T_n)}{T_n}; = \frac{P}{\frac{1}{P}} \frac{T_n^2 (1 - T_n)}{T_n}; (1)$$

where T_n represents the transm ission of the n-th conducting channel of our system . The cumulant S_3 can be expressed in the following general form

$$S_3 = (2 F)^2 i$$
: (2)

Here I is the average current through the conductor, estands for the electron charge, and F is a universal function of frequencies, voltage V and temperature T to be evaluated below . A coording to Eq. (2) the frequency dispersion of S_3 originates only from the term proportional to the parameter while the -term is dispersionless.

Though negligible for tunnel junctions $\,!\,$ 0, the frequency dispersion of S_3 m ay become important in other situations. For instance, at T $\,!\,$ 0 one ndsF $\,!\,$ 1 at frequencies much smaller than eV while in the opposite high frequency lim it one gets F = 0 and, hence, S_3 = $e^2 I$ in the latter lim it. To give some numbers, for an important case of diffusive conductors one has = 1=3 and

2 = 1=15, i.e. in this case the quantity § changes

by the factor 5 depending on whether relevant frequencies are below or above eV . For conductors with $\,<\,2\,$ even the sign of S_3 will dier in these two limits.

In our analysis we will use the real time path integral form alism developed for the systems of interacting ferm ions 14 . A fler the standard Hubbard-Stratonovich decoupling of the interaction term in the Hamiltonian one can exactly integrate out ferm ions and arrive at the elective action S which depends on the uctuating elds $V_{1:2}$ (t;r). Let us de ne

$$e^{iS} = Tr T e^{i\frac{R_t}{0} dt^0 H_1(t^0)} \wedge_0 T e^{i\frac{R_t}{0} dt^0 H_2(t^0)}; \qquad (3)$$

with the trace taken over the ferm ionic variables. Here $^{\circ}_{0}$ is the initial N particle density matrix of electrons,

$$H_{1;2} = X^{Z}$$

$$d^{3}r^{y}(r)H_{1;2}(t)^{(r)}(r);$$

$$H_{1;2}(t) = \frac{r^{2}}{2m} + U(r) \quad eV_{1;2}(t;r)$$
(4)

are the e ective H am iltonians on the forward and backward parts of the K eldysh contour, U (r) describes the static potential, T and T are respectively the forward and backward time ordering operators. Integrating out ferm ions in Eq. (3), we obtain $iS = iS_0 + iS_{em}$ where

$$iS_0 = 2 Tr ln [1 + (\hat{q}_2^1 \hat{q}_1 - 1) \hat{q}_0];$$
 (5)

 $\hat{\mathbf{u}}_{1;2}$ (t) = T exp $\hat{\mathbf{i}}_0^R dt^0 \hat{\mathbf{H}}_{1;2}$ (t⁰) are the evolution operators pertaining to the H am iltonians (4), $\hat{\mathbf{v}}_0$ stands for

the initial single-particle density m atrix and the term $\,S_{\,\text{em}}\,$ accounts for the electrom agnetic contribution which m ay also include the e ect of an external circuit.

In order to evaluate the evolution operators $\hat{u}_{1;2}$ it is necessary to specify the model of a mesoscopic conductor. Here we will adopt the standard model of a (comparatively short) coherent conductor placed in-between two bulk metallic reservoirs. The electron dwell time of is supposed to be shorter than any relevant time scale in our problem. Energy and phase relaxation times are, on the contrary, assumed to be long, i.e. inelastic relaxation is allowed in the reservoirs but not inside the conductor. Under these assumptions electron transport through the conductor can be described by the energy independent scattering matrix

$$\hat{S} = \begin{array}{cc} \hat{r} & \hat{t}^0 \\ \hat{t} & \hat{r}^0 \end{array} \tag{6}$$

and the e ective action (5) can be expressed via the uctuating phase elds ${}'_{1;2}$ which are in turn related to the jumps of the elds $V_{1;2}$ across the scatterer as ${}'_{-1;2} = e(V_{L\,1;2} - V_{R\,1;2})$, where $V_{L\,;R}$ are uctuating in time but constant in space elds in the left and right reservoirs. We note that in this case the right hand side of Eq. (3) diers from the FCS generating functional introduced in Ref. 15 only by a gauge transform ation.

W ithin the above model the evolution operators $\hat{u}_{1;2}$ were evaluated in Refs. 2,10. Combining these expressions with Eq. (5) after some algebra we nd

$$\text{iS}_0 = 2 \text{Tr} \ln \ \hat{1} \ (x \ y) + \ (t \ x) \ (x) \\ \frac{\text{ty} \, \hat{t} \, (\text{e}^{\text{i}'} \ (x)} {2} \, \hat{t}^{\text{ty}} \, \hat{t}^{\text{0}} \, \sin \frac{\text{i}^{\text{x}} \, (x)}{2} }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, \sin \frac{\text{i}^{\text{x}} \, (x)}{2} }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, \sin \frac{\text{i}^{\text{x}} \, (x)}{2} }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, \sin \frac{\text{i}^{\text{x}} \, (x)}{2} }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, (x \ y) + \ (x \ x) \, (x) }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, (x \ y) + \ (x \ x) }{2} \\ \frac{\text{ty} \, \hat{t}^{\text{0}} \, (x \ y) + \ (x \$$

Here we introduced ' = ('₁ + '₂)=2, ' = '₁ '₂ and

$$_{0}(x) = \frac{Z}{2} \frac{dE}{1 + e^{E} - T} :$$
 (8)

Taking the trace in Eq. (7) implies convolution with respect to internal time variables (x and y). The total time span is denoted by t.

Eq. (7) de nes a form ally exact e ective action for a coherent conductor described by an arbitrary energy independent scattering matrix (6). This expression allows to fully determine statistics of current uctuations at arbitrary frequencies and in the presence of interactions. In the case of equilibrium uctuations the formula (7) represents a realtime analogue of the elective action derived in Refs. 16,17 within the Matsubara technique. A formula similar to Eq. (7) was also presented recently

in Ref. 18. In addition we note that, provided the eld does not depend on time, Eq. (7) coincides with the generating function considered, e.g., in the problem of adiabatic pumping through mesoscopic conductors¹⁹.

Let us illustrate the relation between the e ective action (7) and the FCS generating function⁵. For this purpose we (i) disregard interactions and set ' that is even and (ii) suppress uctuations of ' and set ' = const. A fler these simplications from Eq. (7) we obtain

$$iS_{FCS} = \frac{t}{-} Tr \quad dE \quad ln \quad 1 + t^{\prime} t^{\prime} n_{L} (E) (1 \quad n_{R} (E))$$

$$(e^{i'} \quad 1) + t^{\prime} t^{\prime} n_{R} (E) (1 \quad n_{L} (E)) (e^{-i'} \quad 1); (9)$$

where $n_{L;R}$ (E) = 1=[1 + exp[(E eV=2)=T]]. Eq. (9) is just the FCS generating function⁵ which can be used to

recover all cum ulants of the current operator in the zero frequency lim it and in the absence of interactions.

The expression (7) is more general since it includes all possible uctuations of the phase elds '. For instance, if one allows for temporal variations of ', with the aid of Eq. (7) one can easily describe the frequency dispersion of the current correlators. Below we will illustrate this point by directly evaluating the third cumulant of the current operator.

 $\ensuremath{\mathtt{W}}$ ithin our model the current operator can be de ned in a standard manner

$$\hat{\mathbf{I}}(\mathbf{t}) = \frac{e}{2} \frac{d}{d\mathbf{t}} (\hat{\mathbf{N}}_{L}(\mathbf{t}) \quad \hat{\mathbf{N}}_{R}(\mathbf{t})); \tag{10}$$

where $\hat{N}_{L\ (R\)}$ is the total number of electrons in the left (right) lead. Combining this de nition with Eq. (3) for the expectation value one nds

$$Z$$
 $h\hat{I}(t)i= e D' S[']= '(t)e^{iS[']}$:

Sim ilarly one can de ne higher m om ents of the current operator. Here we consider the follow ing correlation functions: $S_2 = h\hat{1}(t_1)\hat{1}(t_2) + \hat{1}(t_2)\hat{1}(t_1)i=2$ and

$$\begin{split} \tilde{S_3} &= \frac{1}{8} \, h \hat{f}(t_1) \, T \, \hat{f}(t_2) \hat{f}(t_3) \, i + h \, T \, \hat{f}(t_2) \hat{f}(t_3) \, \hat{f}(t_1) i \\ &+ h \hat{f}(t_2) \, T \, \hat{f}(t_1) \hat{f}(t_3) \, i + h \, T \, \hat{f}(t_1) \hat{f}(t_3) \, \hat{f}(t_2) i \\ &+ h \hat{f}(t_3) \, T \, \hat{f}(t_1) \hat{f}(t_2) \, i + h \, T \, \hat{f}(t_1) \hat{f}(t_2) \, \hat{f}(t_3) i \\ &+ h T \, \hat{f}(t_1) \hat{f}(t_2) \hat{f}(t_3) i + h T \, \hat{f}(t_1) \hat{f}(t_2) \hat{f}(t_3) i : (11) \end{split}$$

The correlation function S_2 is important because the symmetric combination of voltages V^+ can be viewed as a classical, measurable, voltage¹⁵. The noise is deduced from them easurable product V^+ (t_1) V^+ (t_2); which is related to the symmetric correlator S_2 . Similarly, the measured product V^+ (t_1) V^+ (t_2) V^+ (t_3) is related to the correlation function of the current operators S_3 defined in Eq. (11), see also Refs. 9,15.

Let us now disregard interaction e ects. In this case one should suppress uctuations of ' in the end of the calculation by setting ' $^+$ () = eV and ' () ! 0. Then for the noise correlator one easily nds

$$S'_2 = (ie)^2 - \frac{2}{(t_1) (t_2)} e^{iS_0}$$
 (12)

and a similar expression is obtained for S_3 . Of interest is the irreducible part of the correlator S_3 which reads

$$S_{3} = e^{3} \frac{{}^{3}S_{0}}{{}'(t_{1}) {}'(t_{2}) {}'(t_{3})}, _{=0}$$

$$= S_{3}(t_{1};t_{2};t_{3}) \quad \text{If } (t_{1})\text{iS}(t_{2};t_{3}) \quad \text{If } (t_{2})\text{iS}(t_{1};t_{3})$$

$$\text{If } (t_{3})\text{iS}(t_{1};t_{2}) + 2\text{hf } (t_{1})\text{ihf } (t_{2})\text{ihf } (t_{3})\text{i:}$$

$$(13)$$

It follows im mediately that in order to evaluate the third current cumulant in the absence of interactions it suces

to expand the exact e ective action (7) up to the third order in $^{\prime}\,$,

$$iS_0['] = iS^{(1)}['] + iS^{(2)}['] + iS^{(3)}['];$$
 (14)

keeping the full non-linearity in ' $^{+}$ in each of these term s. The rst two term s of this expansion were evaluated in Ref. 2. Being combined with Eq. (12), the term S $^{(2)}$ ['] allows to recover the well known expression for the shot noise spectrum 1 . Proceeding further with the expansion in ' for the term is $^{(3)}$ one $\, \mathrm{nds}^{10}$

is
$$^{(3)}$$
 ['] = $\frac{i}{6e^{2}R}$ d (' ()) 3 '_+ () (15)
 $\frac{2 i}{3e^{2}R}$ d $_{0}$ d $_{0}$ d $_{2}$ d $_{3}$ ' (1)' (2)' (3)
f(2; 1)f(3; 2)f(1; 3);

where $1=R=(2e^2=h)^P$ _n T_n is the scatterer conductance and

$$f(_{2};_{1}) = \frac{T \sin [('^{+}(_{2}) \quad '^{+}(_{1}))=2]}{\sinh [T(_{2} \quad _{1})]}; \quad (16)$$

Let us substitute the above expressions into Eq. (13) and, after taking derivatives over ', set ' $^+$ () = eV and '! 0. This is su cient provided the time differences \mathbf{j}_1 \mathbf{t}_1 \mathbf{t}_2 \mathbf{j}_1 \mathbf{t}_3 \mathbf{j}_4 exceed the charge relaxation time \mathbf{k}_{RC} and provided eV \mathbf{l}_{RC} : The formula (13) imm ediately yields

$$S_3 = e^2 I (t_1 t_2) (t_1 t_3)$$
 (17)
 $\frac{4 e}{R} f (t_2 t_1) f (t_3 t_2) f (t_1 t_3);$

where f () = T \sin (eV =2)= \sinh (T). Perform ing the Fourier transform ation

$$S_3(!_1;!_2) = d_1d_2e^{i!_1_1+i!_2_2}S_3(t_1;t_1_1;t_1_2)$$

we arrive at the nal result

$$S_3 = e^2 I \quad 2 \stackrel{?}{e} IF (v; w_1; w_2);$$
 (18)

where

$$F = \frac{\sinh^{3}(v=2)}{4v} \begin{bmatrix} Z_{1} \\ & \\ & \\ \end{bmatrix} \frac{d!}{(!) (! w_{1}) (! + w_{2})} : (19)$$

Here we de ned v = eV = T; $w_{1;2} = !_{1;2} = 2T$ and

$$(!) = \cosh^2 ! + \sinh^2 (v=4)$$
: (20)

Eqs. (18)-(20) represent the main result of this paper. They fully describe the third cumulant of the current operator at voltages and frequencies smaller than both $1=_{\rm R.C.}$ and $1=_{\rm R.C.}$

Let us brie y analyze Eqs. (18)-(20) in various lim its. For ! $_{1;2}=0$ we recover the well known result⁷

F
$$(v;0;0) = 1 + 3 \frac{1 + v=v}{\cosh v};$$
 (21)

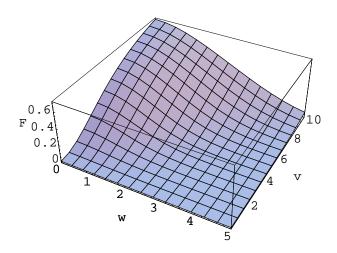


FIG. 1: The function F(v;w;0) = F(v;w;w), see Eq. (19).

which in turn yields F ! 1 in the lim it of large voltages v=1. Eq. (21) also holds for $w_{1;2}=v$.

In the lim it v 1 one nds

F (v 1; w; 0) = F (v 1; w; w) = (22)

$$\frac{9 \sinh w + \sinh (3w)}{48 \sinh^5 w}$$

and, sim ilarly,

F (v 1; w; w) = (23)

$$\frac{\sinh(4w) + 4 \sinh(2w)}{128 \sinh^5 w \cosh^3 w}$$

These equations demonstrate that at large frequencies w 1 the function F decays exponentially with w. From Eqs. (22) and (23) we not respectively F / $v^2e^{-2w}=3$ and F / v^2e^{-4w} .

Finally let us turn to the most interesting lim it of low temperatures, in which case one always has $v; w_1; w_2$ 1. Neglecting small corrections 1=v; 1=w we obtain

F
$$(v; w_1; w_2) = 1$$
 $2 \frac{w_{12}}{v}$; if $2 \dot{w}_{12} \dot{j} < \dot{y} \dot{j}$ (24)
F $(v; w_1; w_2) = 0$; if $2 \dot{w}_{12} \dot{j} > \dot{y} \dot{j}$; (25)

Here the value w_{12} is de ned dierently depending on the sign of the product w_1w_2 . For $w_1w_2 > 0$ we have $w_{12} = w_1 + w_2$ while in the opposite case $w_1w_2 < 0$ we de ne $w_{12} = \max [\dot{y}_1 \dot{j}_1 \dot{y}_2]$. We observe that in both cases the function F depends linearly on frequency and vanishes as soon as \dot{w}_{12} jexceeds \dot{v}_{12} .

At arbitrary values of v, w_1 and w_2 the integral (19) can be evaluated numerically. The corresponding result for the function F(v;w;0) is depicted in Fig. 1. The overall form of the function F(v;w;w) is similar but { as compared to F(v;w;0) { it demonstrates a somewhat faster decay w ith increasing frequency.

In conclusion, we have presented a general approach which allows to describe statistics of current uctuations in mesoscopic coherent conductors at arbitrary frequencies and in the presence of interactions. Restricting ourselves to the non-interacting case, we have analyzed frequency dispersion of the third cumulant of the current operator. This dispersion was found negligible only in the case of tunnel junctions, while in a general case it turns out to be important in the frequency range comparable to eV. Similar results are also expected for higher order cumulants of the current operator.

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